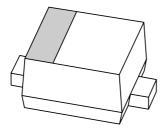
DISCRETE SEMICONDUCTORS

DATA SHEET



1PS79SB30 Schottky barrier diode

Product data sheet 2001 Feb 20



Schottky barrier diode

1PS79SB30

FEATURES

- Very low forward voltage
- · Very low reverse current
- · Guard ring protected
- Ultra small SMD package.

APPLICATIONS

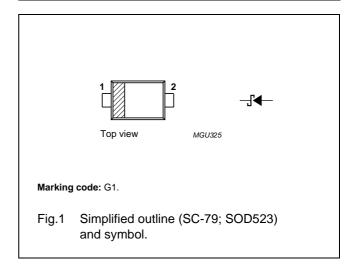
- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- · Blocking diodes
- Low power consumption applications (e.g. hand-held applications).

DESCRIPTION

Planar Schottky barrier diode encapsulated in a SC-79 (SOD523) ultra small SMD plastic package.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	40	V
I _F	continuous forward current		-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	300	mA
I _{FSM}	non-repetitive peak forward current	t = 8.3 ms half sinewave; JEDEC method	_	1	А
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	forward voltage	see Fig.2			
		I _F = 0.1 mA	190	220	mV
		I _F = 1 mA	250	290	mV
		I _F = 10 mA	320	360	mV
		I _F = 100 mA	440	500	mV
		I _F = 200 mA	520	600	mV
I _R	continuous reverse current	V _R = 25 V; note 1; see Fig.3	_	0.5	μΑ
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; see Fig.4	_	20	pF

Note

1. Pulse test: pulse width = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	450	K/W

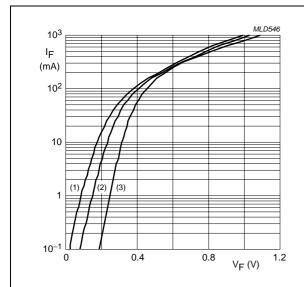
Note

1. Refer to SC-79 (SOD523) standard mounting conditions.

Schottky barrier diode

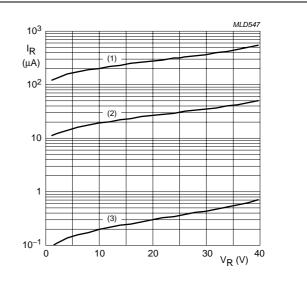
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GRAPHICAL DATA



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.

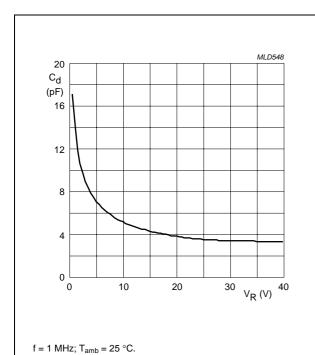


Fig.4 Diode capacitance as a function of reverse voltage; typical values.

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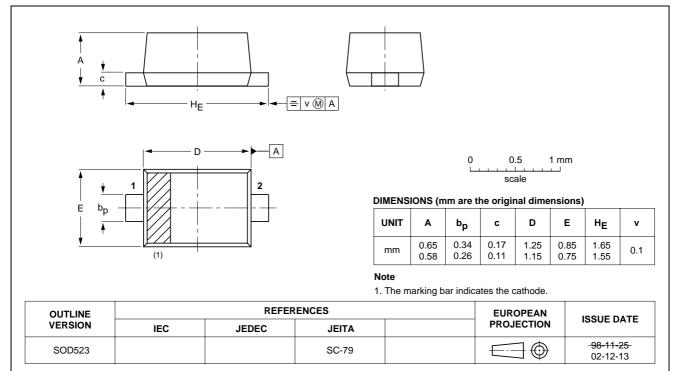
Schottky barrier diode

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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD523



Schottky barrier diode

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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Printed in The Netherlands 613514/01/pp7 Date of release: 2001 Feb 20 Document order number: 9397 750 07938

